International Rectifier

10MQ060NPbF

SCHOTTKY RECTIFIER

2.1 Amp

$$I_{F(AV)} = 2.1 Amp$$

 $V_R = 60 V$

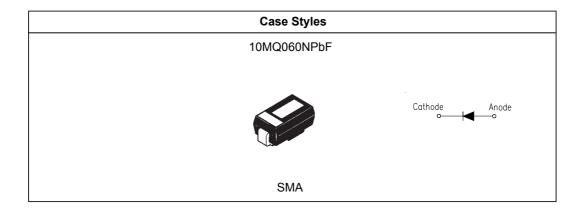
Major Ratings and Characteristics

Characteristics	Value	Units
I _F DC	2.1	Α
V _{RRM}	60	V
I _{FSM} @tp=5µssine	40	А
V _F @1.5Apk, T _J =125°C	0.63	V
T _J range	- 55 to 150	°C

Description/ Features

The 10MQ060NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)



Voltage Ratings

	Part number	10MQ060NPbF	
V_R	Max. DC Reverse Voltage (V)		
V _{RWM} Max. Working Peak Reverse Voltage (V)		60	

Absolute Maximum Ratings

	Parameters	10MQ	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current *See Fig. 4	1.5	Α	50% duty cycle @ T _L = 120 °C, rectangular wave fo On PC board 9mm ² island(.013mm thick copper pad	
I _{FSM}	Max. Peak One Cycle Non-Repetitive	40	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V _{RRM} applied
	Surge Current * See Fig. 6	10	, ,	10ms Sine or 6ms Rect. pulse	
E _{AS}	Non-Repetitive Avalanche Energy	2.0	mJ	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1\text{A}, L = 4\text{mH}$	
I _{AR}	Repetitive Avalanche Current	1.0	Α		

Electrical Specifications

	Parameters	10MQ	Units		Conditions
V _{FM}	Max. Forward Voltage Drop (1)	0.63	V	@ 1A	T = 25 °C
	* See Fig. 1	0.71	V	@ 1.5A	T _J = 25 °C
		0.57	V	@ 1A	T ₁ = 125 °C
		0.63	V	@ 1.5A	1 _J = 125 C
I _{RM}	Max. Reverse Leakage Current (1)	0.5	mA	T _J = 25 °C	V = rated V
	* See Fig. 2	7.5	mA	T _J = 125 °C	V _R = rated V _R
V _{F(TO}	Threshold Voltage	0.45	V	T _J = T _J max.	
r _t	Forward Slope Resistance	86.8	mΩ		
Ст	Typical Junction Capacitance	31	pF	$V_R = 10V_{DC}$, $T_J = 25^{\circ}C$, test signal = 1Mhz	
Ls	Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V _R)	

⁽¹⁾ Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	10MQ	Units	Conditions
T_J	Max. Junction Temperature Range (*)	-55 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-55 to 150	°C	
R _{thJA}	Max. Thermal Resistance Junction	80	°C/W	DC operation
	to Ambient			
wt	Approximate Weight	0.07(0.002)	g (oz.)	
	Case Style	SMA		Similar D-64
	Device Marking	IR1H		

 $[\]frac{\binom{*}{d}}{dTj} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

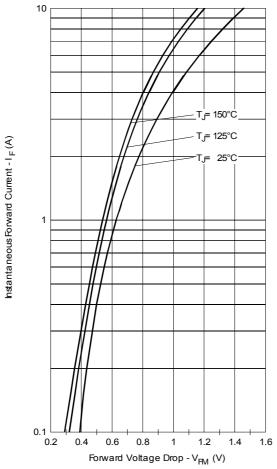


Fig. 1 - Maximum Forward Voltage Drop Characteristics

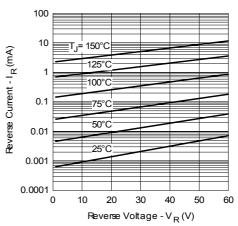


Fig. 2-Typical Peak Reverse Current Vs. Reverse Voltage

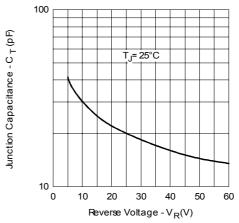


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

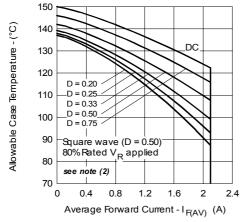


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

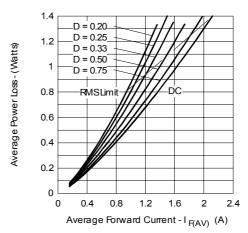


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

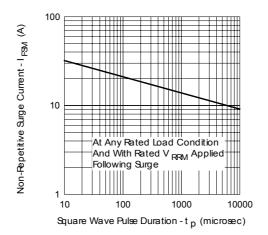
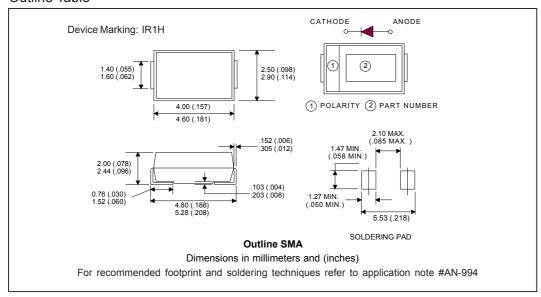


Fig. 6-Maximum Peak Surge Forward Current Vs. Pulse Duration

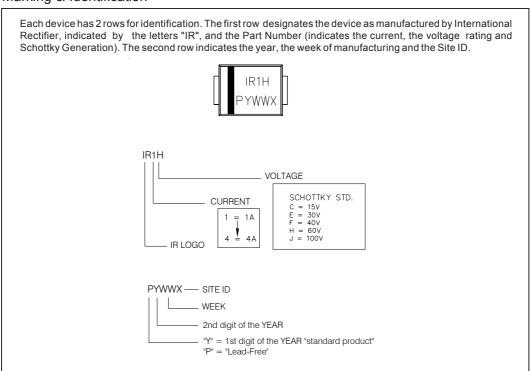
 $\begin{aligned} \textbf{(2)} \ \ &\text{Formula used:} \ &T_{\text{C}} = T_{\text{J}} \cdot (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ &\text{Pd} = \text{Forward Power Loss} = &I_{\text{F(AV)}} \times V_{\text{FM}} \textcircled{0} \left(I_{\text{F(AV)}} / D\right) \ \ (\text{see Fig. 6}); \\ &\text{Pd}_{\text{REV}} = &\text{Inverse Power Loss} = &V_{\text{R1}} \times I_{\text{R}} (1 - D); \ I_{\text{R}} \textcircled{0} V_{\text{R1}} = &80\% \ \text{rated} \ V_{\text{R}} \end{aligned}$

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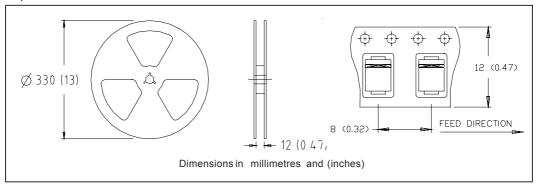
Outline Table



Marking & Identification

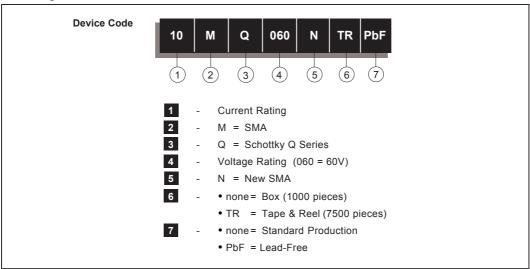


Tape & Reel Information



Ordering Information Table

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Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free.

Qualification Standards can be found on IR's Web site.



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